

**2DEG under microwaves:
oscillatory photoresistivity and zero-resistance states**

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Dmitriev, ADM, Polyakov, PRL 91, 226802 (2003), cond-mat/0403598

Dmitriev, Vavilov, Aleiner, ADM, Polyakov, cond-mat/0310668

Andreev, Aleiner, Millis, PRL 91, 056803 (2003)

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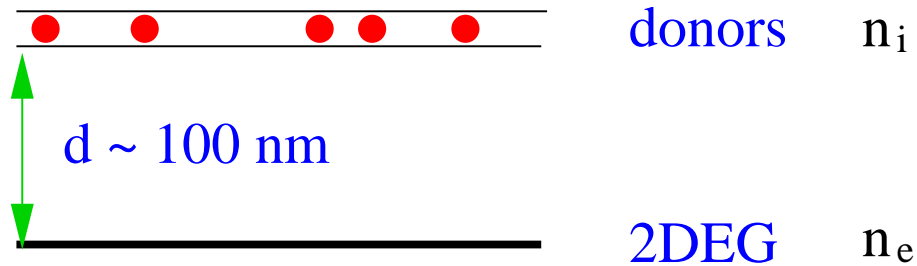
Outline:

- Introduction: 2DEG magnetotransport
- Recent experiments:
Oscillatory PhotoConductivity and Zero-Resistance States
- Microscopic theory:
 - Oscillatory ac conductivity due to interplay of Landau quantization and disorder
 - OPC due to microwave-induced oscillations in the distribution function
- From OPC to ZRS: spontaneous domain formation
- Theory vs. experiment
- Summary & Outlook

2D electron gas in strong magnetic fields

Standard realization: GaAs/AlGaAs heterostructures

Disorder: charged donors



Typical experimental parameters:

$$n_e \sim n_i \sim (1 \div 3) \cdot 10^{11} \text{ cm}^{-2}, \quad d \sim 100 \text{ nm}$$

$$\longrightarrow k_F d \sim 10 \gg 1$$

weak long-range disorder

$$\longrightarrow \text{high mobility}$$

$$\frac{\tau}{\tau_q} \sim (k_F d)^2 \gg 1$$

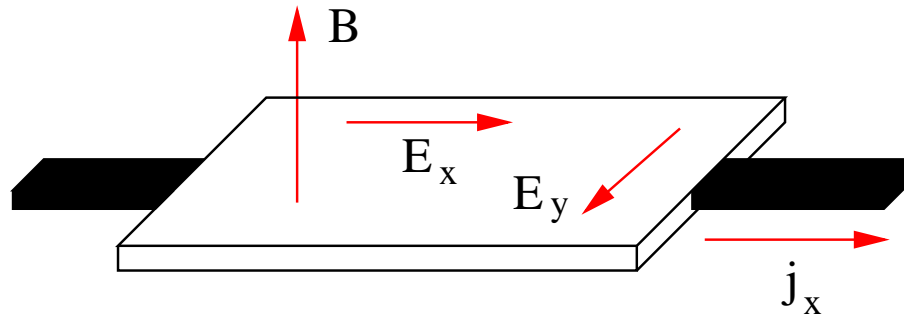
τ, τ_q – transport and single-particle relaxation times

Magnetotransport

resistivity tensor:

$$\rho_{xx} = E_x / j_x$$

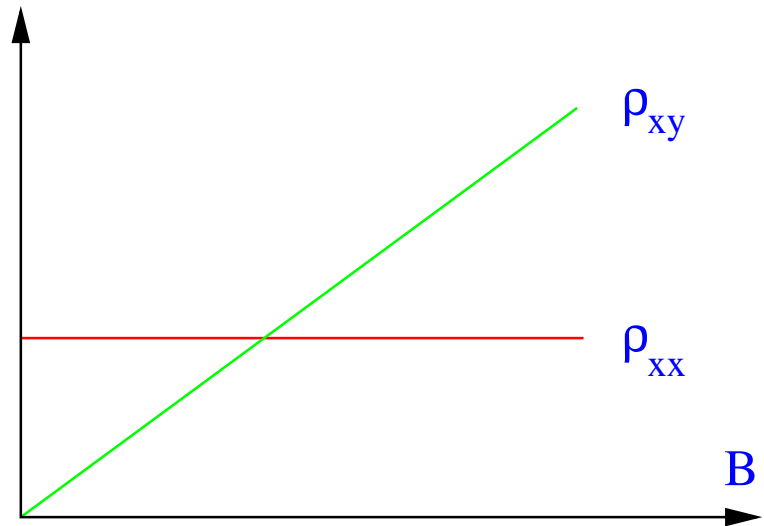
$$\rho_{yx} = E_y / j_x \quad \text{Hall resistivity}$$



classically (Drude–Boltzmann theory):

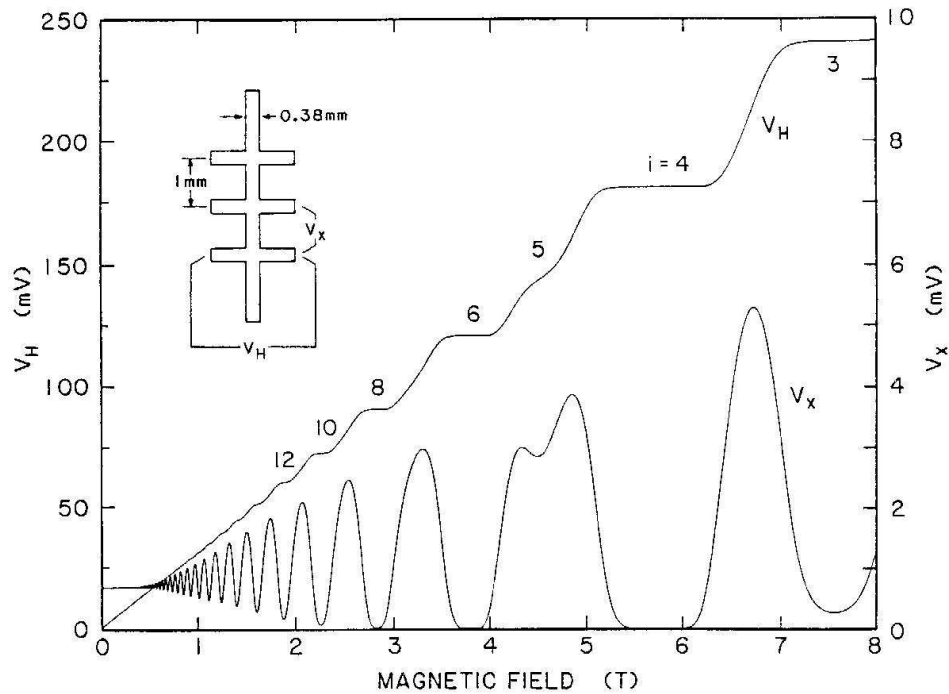
$$\rho_{xx} = \frac{m}{e^2 n_e \tau} \quad \text{independent of } B$$

$$\rho_{yx} = -\frac{B}{n_e e c}$$

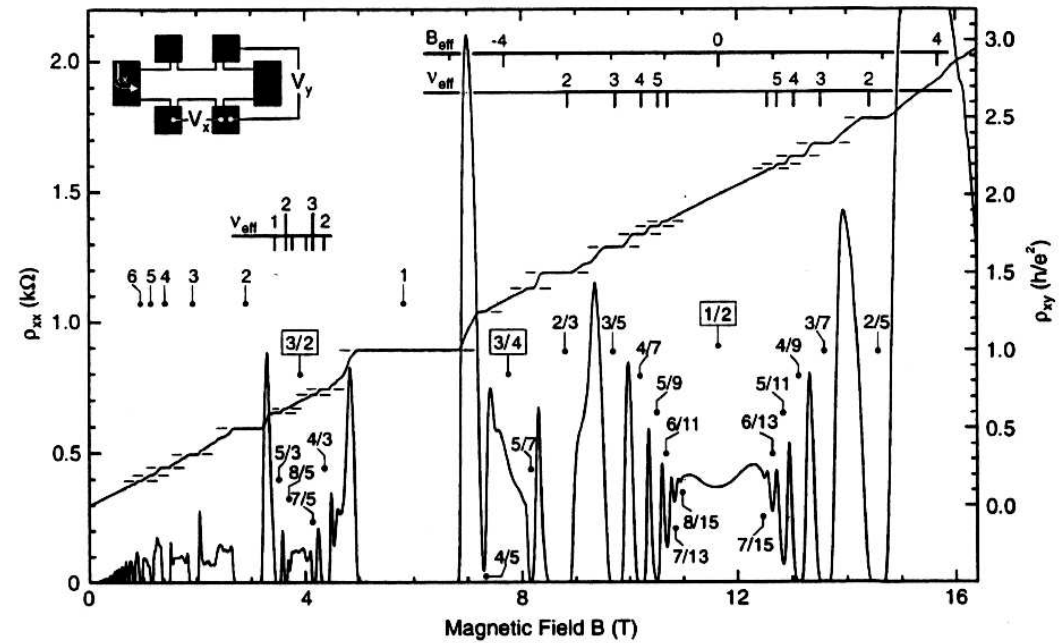


Quantum transport in strong magnetic fields

Shubnikov - de Haas Oscillations and
Integer Quantum Hall Effect (IQHE)



Fractional Quantum Hall Effect
(FQHE)



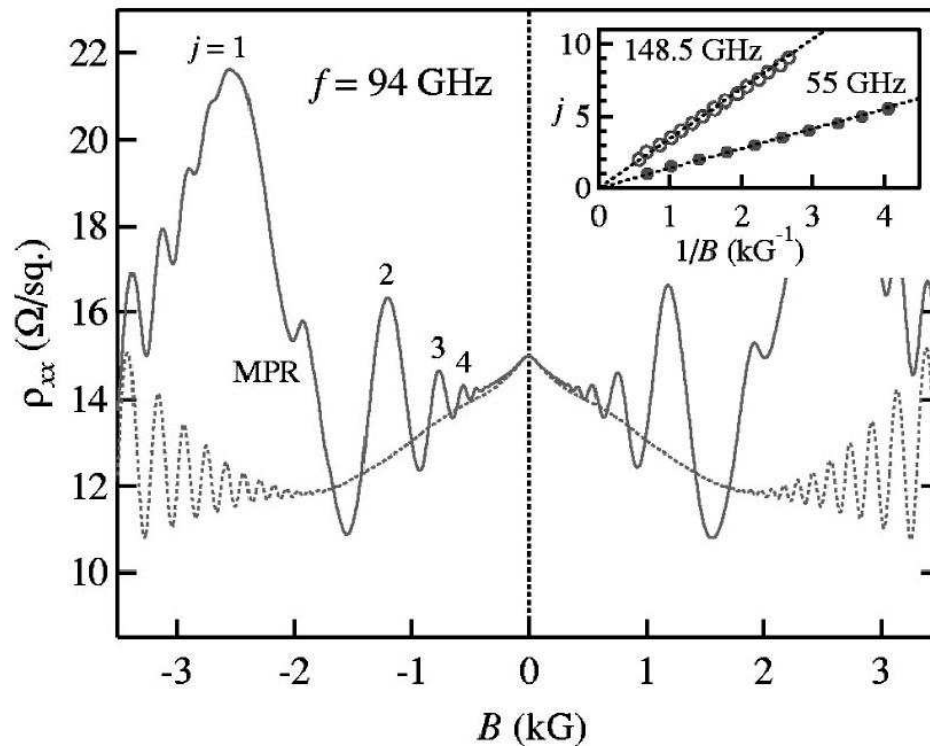
composite fermions:
 $e^- + 2$ flux quanta

Experiment: Oscillatory photoresistance

Photoresistivity: DC response of a 2DEG subjected to microwave radiation

Zudov, Du, Simmons, and Reno, cond-mat/9711149; PRB (2001)

- High-mobility 2DEG $\mu = 3 \times 10^6 \text{ cm}^2/\text{Vs}$
- Microwave radiation at $\omega/2\pi = 30 - 150 \text{ GHz}$



→ Oscillations governed by ω/ω_c

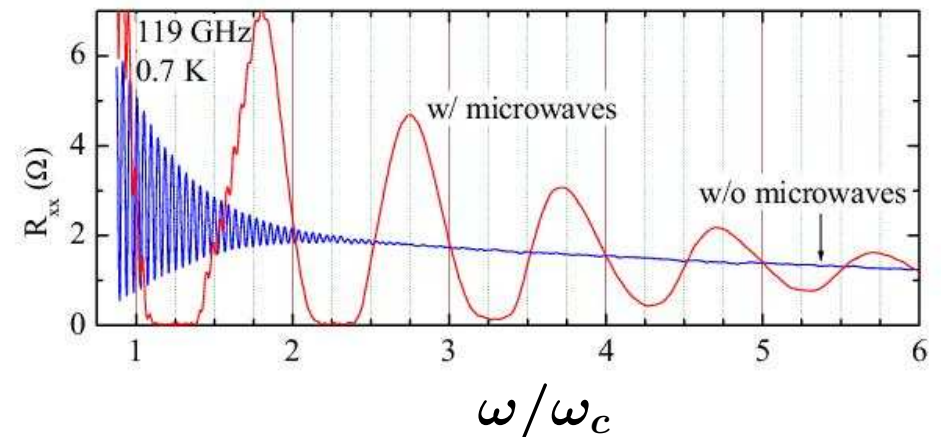
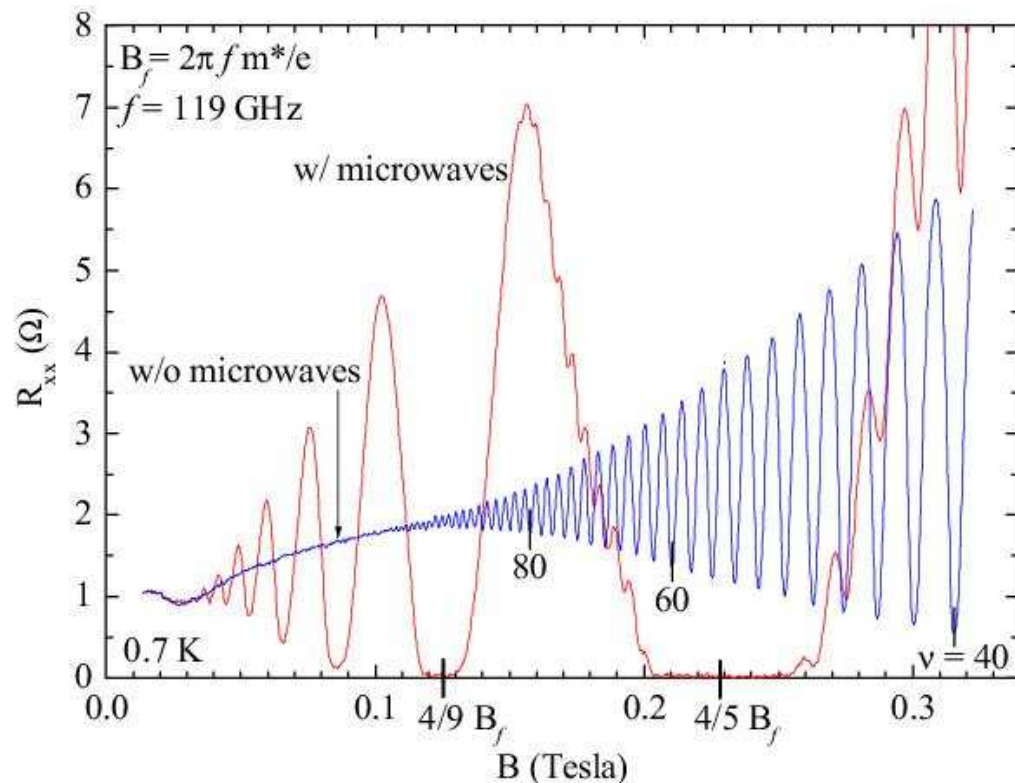
Experiment: Zero-resistance states

Mani, Smet, von Klitzing, Narayanamurti, Johnson, Umansky,

Nature (2002); ...

Zudov, Du, Pfeiffer, West, PRL (2003); ...

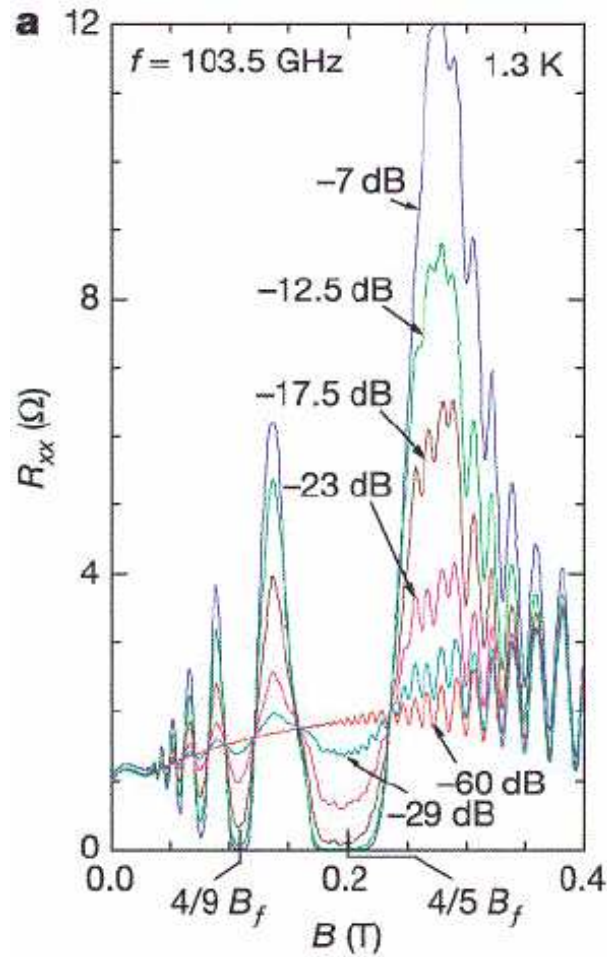
- ultra-high-mobility 2DEG $\mu = 1.5 \div 3 \times 10^7 \text{ cm}^2/\text{Vs}$



Experiment \longrightarrow

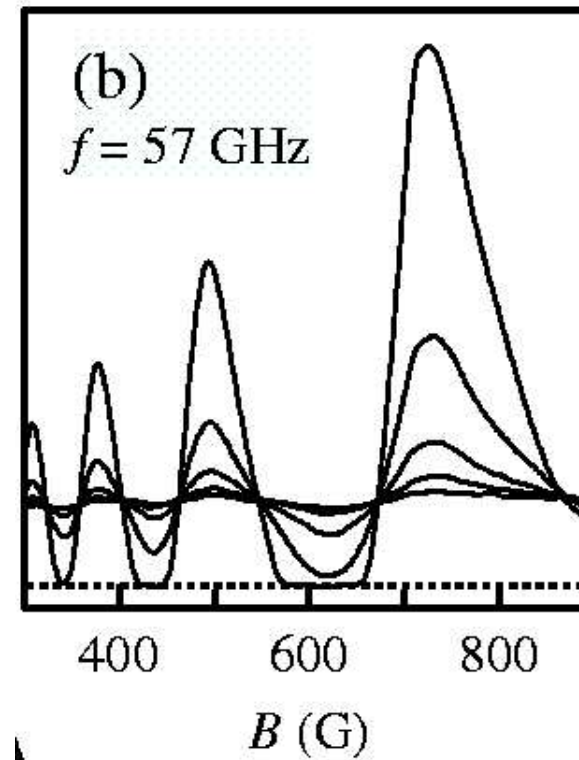
$$\Delta\rho \propto -\sin\left(\frac{2\pi\omega}{\omega_c}\right) \exp(-\pi/\omega_c\tau^*)$$

Experiment: Dependence on microwave power



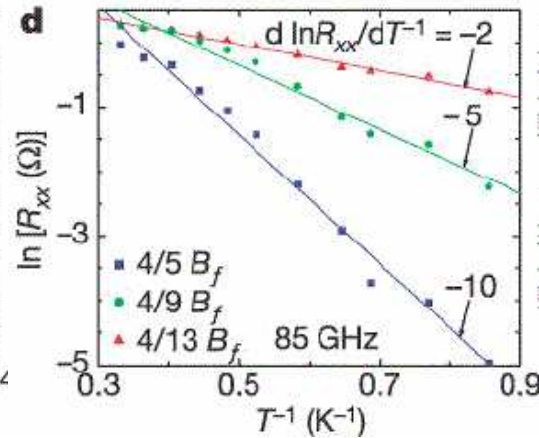
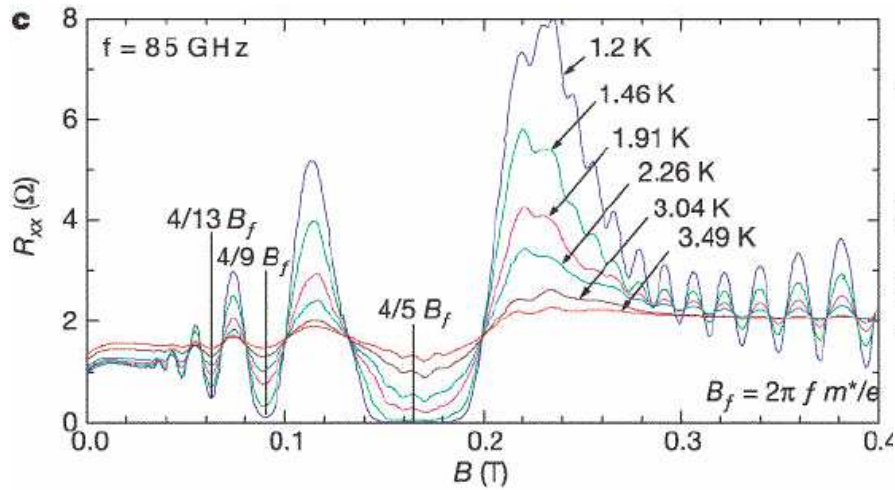
Mani et al.

Zudov et al.

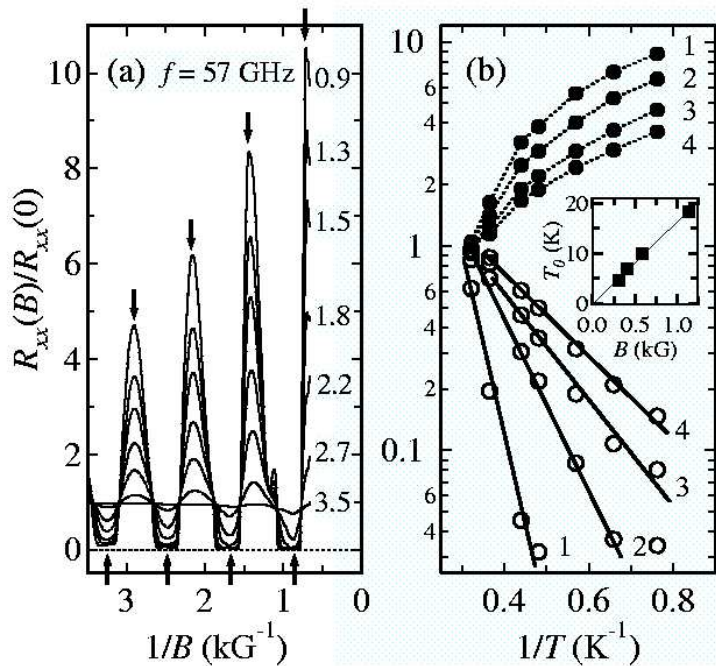


- Maxima: $\delta\rho \propto P$
- Minima: $\rho \simeq 0$ at sufficiently strong P

Experiment: Temperature dependence



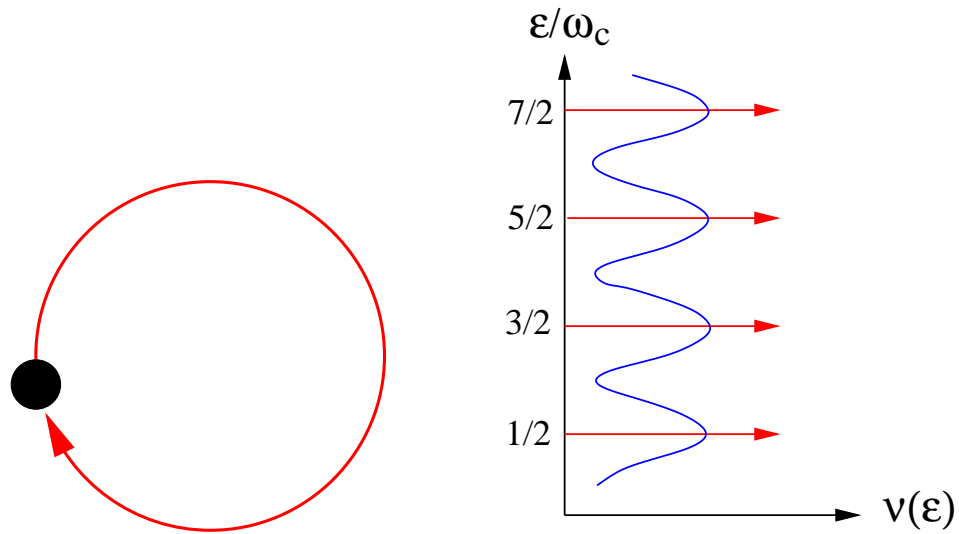
Mani et al.



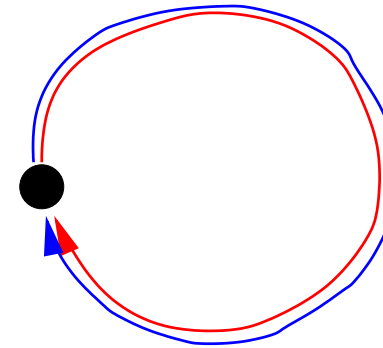
- Oscillations strongly enhanced with decreasing T
- Minima: $\rho \rightarrow 0$
Zero-resistance regions
seemingly activated behavior $e^{-T_0/T}$ with large $T_0 \sim 10$ K

Zudov et al.

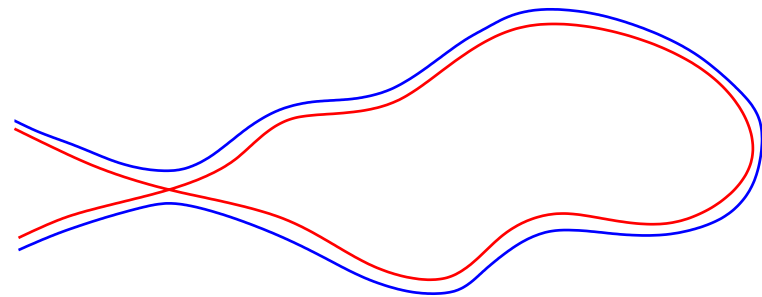
Beyond the Drude model: Return processes



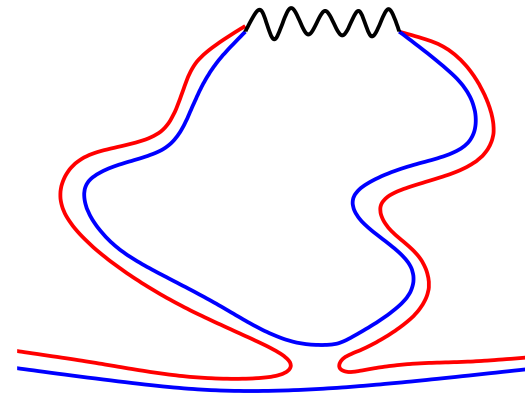
Landau quantization



quasiclassical memory effects



weak localization



interaction corrections

Oscillatory ac conductivity of a 2DEG

- sufficiently strong disorder \longrightarrow constant DOS ν_0 , no LLs \longrightarrow

Drude theory: $\sigma_{xx}(\omega) = \sigma_+(\omega) + \sigma_-(\omega)$

$$\sigma_{\pm}^{(D)}(\omega) = \frac{e^2 \nu_0 v_F^2 \tau_{\text{tr},0}}{4[1 + (\omega_c \pm \omega)^2 \tau_{\text{tr},0}^2]}$$

\longrightarrow only one cyclotron peak at $\omega_c = \omega$

- no disorder, sharp LLs \longrightarrow Kohn theorem

\longrightarrow absorption at $\omega = \omega_c$ only.

- weak disorder \longrightarrow oscillatory DOS

\longrightarrow LLs mixed by disorder

\longrightarrow cyclotron resonance **harmonics** at $\omega_c = \omega/n$.

• **Disorder** $U(\mathbf{r})$: $\langle U(\mathbf{r})U(\mathbf{r}') \rangle = W(|\mathbf{r} - \mathbf{r}'|)$

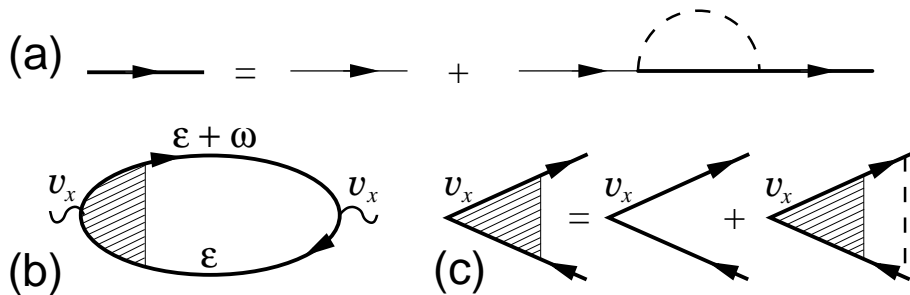
$B = 0$: **Quantum** and **transport** relaxation times:

$$\left. \begin{array}{l} \tau_{q,0}^{-1} \\ \tau_{tr,0}^{-1} \end{array} \right\} = 2\pi\nu_0 \int \frac{d\phi}{2\pi} \tilde{W}(2k_F \sin \frac{\phi}{2}) \times \begin{cases} 1 \\ (1 - \cos \phi) \end{cases}$$

White noise $\longrightarrow W(\mathbf{r}) = \frac{1}{2\pi\nu_0\tau_0} \delta(\mathbf{r}) \implies \tau_{q,0} = \tau_{tr,0} = \tau_0$

Smooth disorder \longrightarrow correlation length $d \gg k_F^{-1} \implies$
 $\tau_{tr,0}/\tau_{q,0} \sim (k_F d)^2 \gg 1$

• **Self-Consistent Born Approximation:**



validity conditions: $d \ll v_F \tau_{q,0}$, $d \ll \lambda_B = \left(\frac{c}{eB}\right)^{1/2}$

Oscillatory ac conductivity of a 2DEG

$$\sigma(\omega) = \sum_{\pm} \frac{e^2 v_F^2}{4\omega} \int d\varepsilon \frac{(f_{\varepsilon} - f_{\varepsilon+\omega}) \nu(\varepsilon) \tau_{\text{tr}}^{-1}(\varepsilon + \omega)}{(\omega \pm \omega_c)^2 + \frac{1}{2} [\tau_{\text{tr}}^{-2}(\varepsilon) + \tau_{\text{tr}}^{-2}(\varepsilon + \omega)]}$$

$\nu(\varepsilon)$ – DOS, $\tau_{\text{tr}}(\varepsilon) = \frac{\tau_{\text{tr},0} \nu_0}{\nu(\varepsilon)}$ – transport time, depends on ε and B due to $\nu(\varepsilon)$

Overlapping Landau levels: LL width $> \omega_c$

• DOS $\nu = \nu_0 [1 - 2\delta \cos 2\pi\varepsilon/\omega_c]$ $\delta = \exp(-\pi/\omega_c \tau_q) \ll 1$

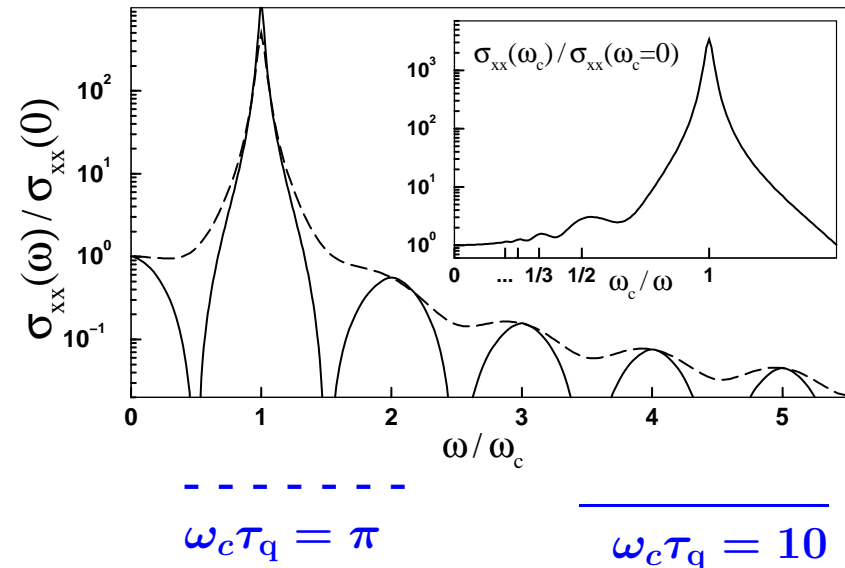
• Order δ^1 : $\sigma(\omega) = \sigma^D(\omega) \left[1 - 4\delta \cos(2\pi\varepsilon_F/\omega_c) \frac{\sin(2\pi\omega/\omega_c)}{2\pi\omega/\omega_c} \right]$

$\omega = 0 \longrightarrow$ SdH oscillations

$T > \frac{\omega_c}{2\pi^2} \longrightarrow$ suppressed $\propto e^{-2\pi^2 T/\omega_c}$

• Order δ^2 : survives at high T !

$$\frac{\sigma(\omega)}{\sigma^D(\omega)} = [1 + 2 e^{-2\pi/\omega_c \tau_q} \cos(2\pi\omega/\omega_c)]$$

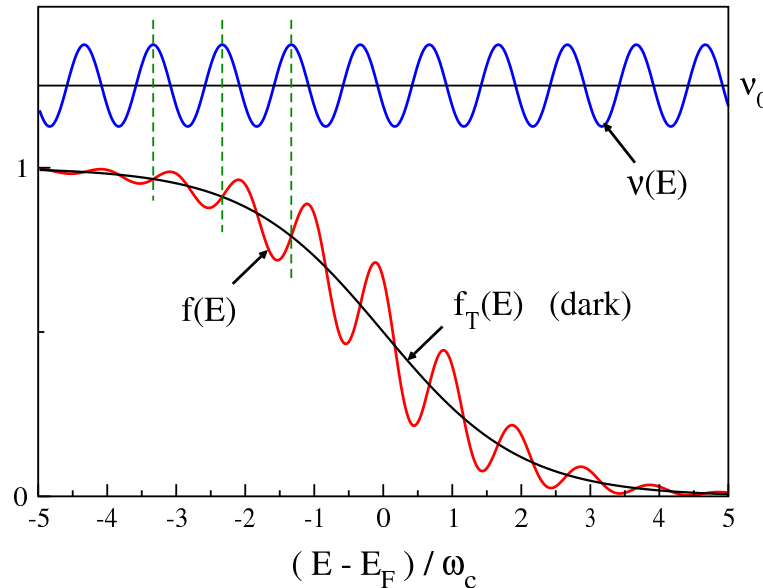
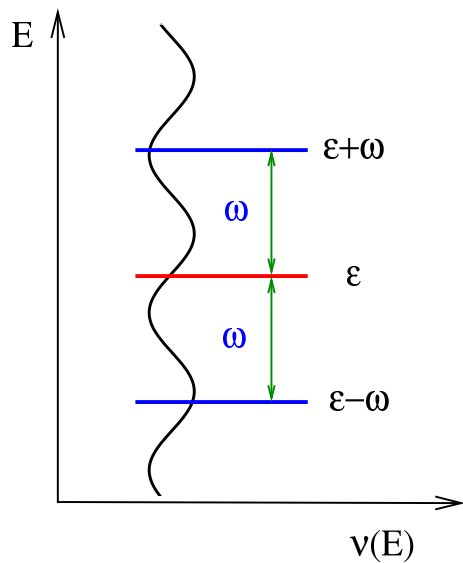


Photoconductivity theory: distribution function oscillations

ac conductivity \iff absorbed power \implies change of distribution function f_ϵ

$$\sigma(\omega) \simeq \omega^2 |M(\omega)|^2 \int \frac{d\epsilon}{\omega} (f_\epsilon - f_{\epsilon+\omega}) \nu(\epsilon) \nu(\epsilon + \omega) \quad |M(\omega)|^2 = \frac{\sigma^{(D)}(\omega)}{\omega^2 \nu_0^2}$$

$$\delta f_\epsilon = \frac{1}{2} |M(\omega)|^2 [(f_{\epsilon-\omega} - f_\epsilon) \nu_{\epsilon-\omega} - (f_\epsilon - f_{\epsilon+\omega}) \nu_{\epsilon+\omega}] E_\omega^2 \tau_{in} \quad \tau_{in} - \text{inelastic relaxation time}$$



$$\delta f_\epsilon = \delta \cdot \tau_{in} \cdot E_\omega^2 \sin \frac{2\pi\omega}{\omega_c} \sin \frac{2\pi\epsilon}{\omega_c} \nu_0 \omega |M(\omega)|^2 \left(\frac{\partial f_T}{\partial \epsilon} \right)$$

Microwave-induced oscillatory δf_ϵ

$\delta f_\epsilon \implies$ Photoconductivity

$$\sigma_{\text{ph}} - \sigma_{\text{dc}} = \sigma_{\text{dc}}^{\text{D}} \int d\epsilon \left(-\frac{\partial \delta f_\epsilon}{\partial \epsilon} \right) \frac{\nu^2(\epsilon)}{\nu_0^2} = -4\sigma_{\text{dc}}^{\text{D}} \delta^2 P_\omega \frac{\pi\omega}{\omega_c} \sin \frac{2\pi\omega}{\omega_c}$$

$$P_\omega = \frac{2\sigma^{\text{D}}(\omega)}{\omega^2\nu_0} E_\omega^2 \tau_{\text{in}} \quad - \text{ dimensionless microwave power}$$

Non-linear photoconductivity: Kinetic equation

Quantum kinetic equation for the distribution function $f(\varepsilon)$:

$$\mathcal{E}_\omega^2 \frac{\sigma^D(\omega)}{2\omega^2\nu_0^2} \sum_{\pm} \nu(\varepsilon \pm \omega) [f(\varepsilon \pm \omega) - f(\varepsilon)] + \frac{\mathcal{E}_{dc}^2 \sigma_{dc}^D}{\nu_0^2 \nu(\varepsilon)} \frac{\partial}{\partial \varepsilon} \left[\nu^2(\varepsilon) \frac{\partial}{\partial \varepsilon} f(\varepsilon) \right] = \frac{f(\varepsilon) - f_T(\varepsilon)}{\tau_{in}}$$

Dimensionless units for the strength of ac and dc fields:

$$\mathcal{P}_\omega = \frac{\tau_{in}}{\tau_{tr}} \left(\frac{e\mathcal{E}_\omega v_F}{\omega} \right)^2 \frac{\omega_c^2 + \omega^2}{(\omega^2 - \omega_c^2)^2}, \quad \mathcal{Q}_{dc} = \frac{2\tau_{in}}{\tau_{tr}} \left(\frac{e\mathcal{E}_{dc} v_F}{\omega_c} \right)^2 \left(\frac{\pi}{\omega_c} \right)^2$$

Overlapping LLs $\longrightarrow \delta = e^{-\pi/\omega_c \tau_q} \ll 1 \longrightarrow$ look for a solution in the form

$$f(\varepsilon) = f_T(\varepsilon) + f_{osc}(\varepsilon) + O(\delta^2), \quad f_{osc}(\varepsilon) \equiv \delta \operatorname{Re} \left[f_1(\varepsilon) e^{i\frac{2\pi\varepsilon}{\omega_c}} \right].$$

\longrightarrow oscillations in non-equilibrium distribution function:

$$f_{osc}(\varepsilon) = \delta \frac{\omega_c}{2\pi} \frac{\partial f_T}{\partial \varepsilon} \sin \frac{2\pi\varepsilon}{\omega_c} \frac{\mathcal{P}_\omega \frac{2\pi\omega}{\omega_c} \sin \frac{2\pi\omega}{\omega_c} + 4\mathcal{Q}_{dc}}{1 + \mathcal{P}_\omega \sin^2 \frac{\pi\omega}{\omega_c} + \mathcal{Q}_{dc}}$$

\longrightarrow oscillatory photoconductivity

Non-linear photoconductivity: Results

$$\frac{\sigma_{\text{ph}}}{\sigma_{\text{dc}}^{\text{D}}} = 1 + 2\delta^2 \left[1 - \frac{\mathcal{P}_\omega \frac{2\pi\omega}{\omega_c} \sin \frac{2\pi\omega}{\omega_c} + 4\mathcal{Q}_{\text{dc}}}{1 + \mathcal{P}_\omega \sin^2 \frac{\pi\omega}{\omega_c} + \mathcal{Q}_{\text{dc}}} \right]$$

● Linear response: $\mathcal{Q}_{\text{dc}} \rightarrow 0$

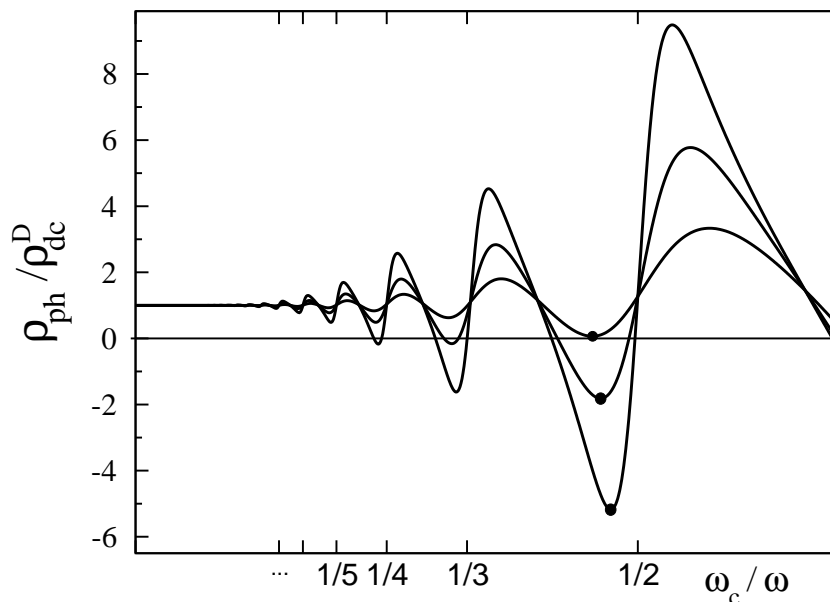
● not too strong $\mathcal{P}_\omega \rightarrow$ linear-in- \mathcal{P}_ω correction

● strong $\mathcal{P}_\omega \rightarrow$ saturation: $\frac{\sigma_{\text{ph}}}{\sigma_{\text{dc}}} = 1 - 8\delta^2 \frac{\pi\omega}{\omega_c} \cot \frac{\pi\omega}{\omega_c}$, $\mathcal{P}_\omega \sin^2 \frac{\pi\omega}{\omega_c} \gg 1$

\rightarrow despite $\delta^2 \ll 1$, correction large near $\omega = k\omega_c$

$\rightarrow \sigma_{\text{ph}} < 0$ around minima for $\mathcal{P}_\omega > \mathcal{P}_\omega^* = \left(4\delta^2 \frac{\pi\omega}{\omega_c} \sin \frac{2\pi\omega}{\omega_c} - \sin^2 \frac{\pi\omega}{\omega_c} \right)^{-1}$

threshold power



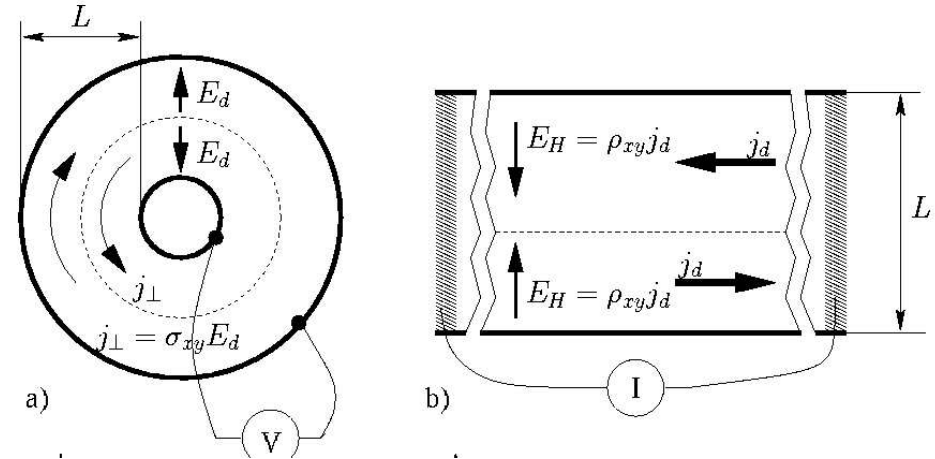
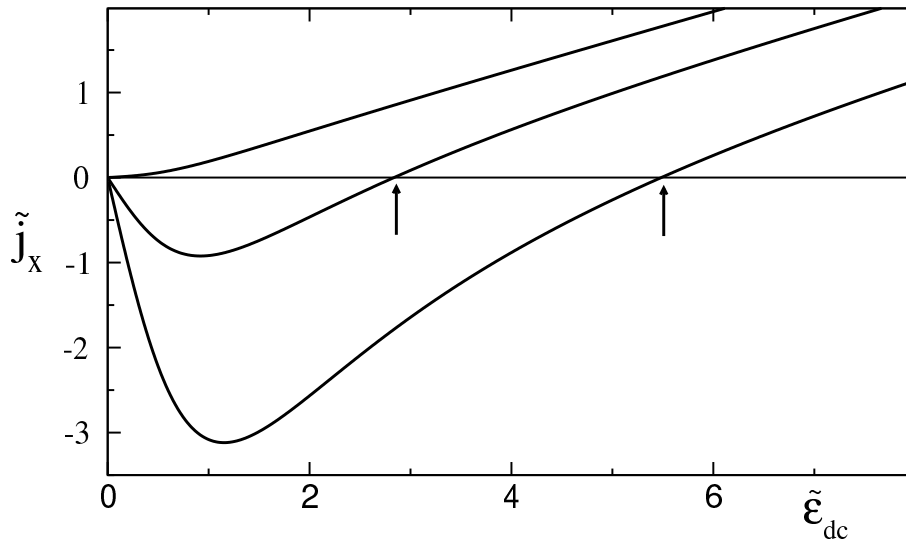
$\rho_{\text{ph}} / \rho_{\text{dc}}^{(D)}$ vs ω_c / ω

$\omega\tau_{q,0} = 2\pi$

$\mathcal{P}_\omega^{(0)} \equiv \mathcal{P}_\omega (\omega_c = 0) = \{0.24, 0.8, 2.4\}$

I-V characteristics and Zero-Resistance States

Current-voltage characteristics at the minima:



Linear response σ_{ph} negative \longrightarrow instability \longrightarrow domains

\longrightarrow zero-resistance state

spontaneous field $\mathcal{E}_{\text{dc}}^*$ in the domains: determined from $\sigma_{\text{ph}}(\mathcal{E}_{\text{dc}}^*) = 0$

$$e\mathcal{E}_{\text{dc}}^* = \frac{\omega_c}{\pi R_c} \left(\frac{\tau_{\text{tr}}}{2\tau_{\text{in}}} \right)^{1/2} \left[\left(\frac{\mathcal{E}_\omega}{\mathcal{E}_\omega^*} \right)^2 - 1 \right]^{1/2} \longrightarrow \mathcal{E}_{\text{dc}}^* \sim 1 \text{ V/cm}$$

can be measured by a local probe: Willett, Pfeiffer, West, PRL 2004

Stability conditions and Zero-Resistance States

Andreev, Aleiner, Millis, PRL 2003

$$\frac{\partial n}{\partial t} = \nabla \mathbf{j} = 0 \quad \text{continuity}$$

$$\mathbf{E} = -\nabla \phi = -\nabla U n \quad \text{Poisson}$$

$$\mathbf{j} = \hat{\sigma}(\mathbf{E})\mathbf{E}$$

U – Coulomb interaction

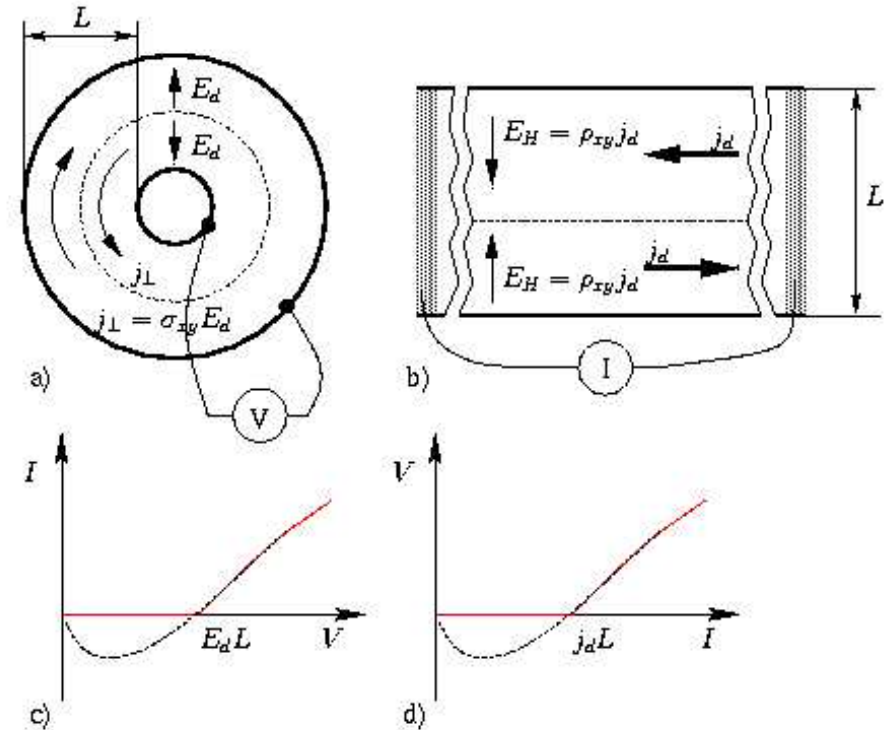
→ Evolution equation for fluctuations

$\delta n(\mathbf{r}, t)$:

$$\frac{\partial}{\partial t} \delta n = \nabla \left[\hat{\sigma} + E \frac{d\hat{\sigma}}{dE} \frac{\mathbf{E} \otimes \mathbf{E}}{E^2} \right] \nabla U \delta n$$

Stability conditions: $\text{Re}(\text{eigenvalues}) > 0$ →

$$\sigma_{xx} = \frac{j_x}{E_x} \geq 0 \quad \text{and} \quad \sigma_{xx} + E \frac{d\sigma_{xx}}{dE} = \frac{\partial j_x}{\partial E_x} \geq 0$$



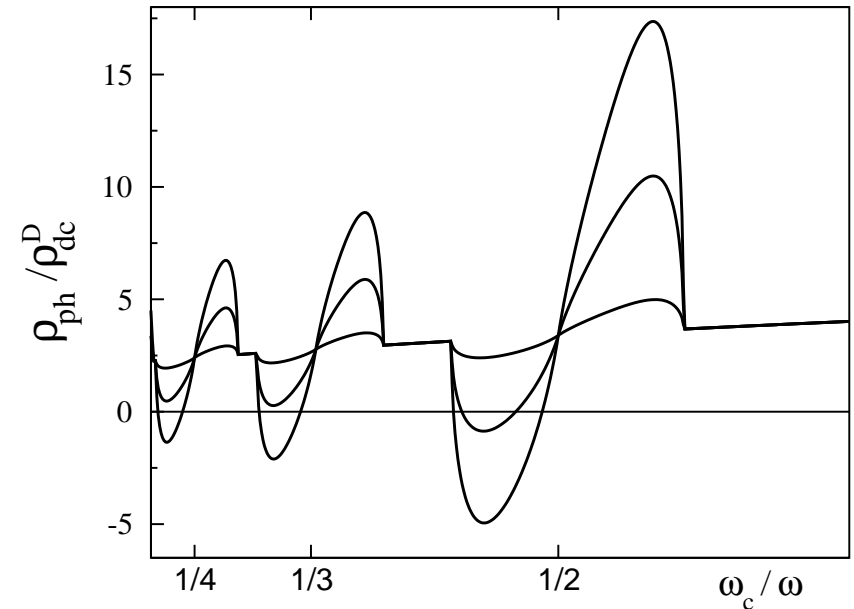
Photoresistivity: Separated LLs

$$\frac{\omega_c \tau_q}{\pi} \gg 1 \longrightarrow \text{separated LLs, width } 2\Gamma = 2 \left(\frac{2\omega_c}{\pi\tau_q} \right)^{1/2}$$

Linear response ($\mathcal{Q}_{\text{dc}} \rightarrow 0$) photoconductivity:

$$\frac{\sigma_{\text{ph}}}{\sigma_{\text{dc}}^{\text{D}}} \simeq \frac{16\omega_c}{3\pi^2\Gamma} \left[1 - \mathcal{P}_\omega \frac{\omega\omega_c}{\Gamma^2} \sum_n \Phi \left(\frac{\omega - n\omega_c}{\Gamma} \right) \right]$$

$$\Phi(x) = \frac{3x}{4\pi} \text{Re} \left[\arccos(|x| - 1) - \frac{1 - |x|}{3} \sqrt{|x|(2 - |x|)} \right]$$



Linear-response $\sigma_{\text{ph}} < 0$ around minima \longrightarrow **ZRS**

strong \mathcal{E}_{dc} : $\sigma_{\text{ph}}(\mathcal{E}_{\text{dc}})$ positive only if inter-LL elastic impurity scattering efficient

\longrightarrow stronger spontaneous field $\mathcal{E}_{\text{dc}}^* \simeq \left(\frac{\tau_{\text{tr}}}{\tau_q} \right)^{1/2} \frac{\omega_c^2}{e v_F}$

Temperature dependence: Inelastic relaxation time

For not too strong microwave power:

$$\sigma_{\text{ph}} - \sigma_{\text{dc}} \propto \mathcal{P}_{\omega} \propto \tau_{\text{in}}$$

Dominant relaxation mechanisms:

smooth part of the distribution function $f_T(\varepsilon) \longrightarrow$ phonons

oscillatory part $f_{\text{osc}}(\varepsilon) \longrightarrow$ **e-e collisions**

$$\frac{1}{\tau_{ee}} = \frac{\pi T^2}{4\epsilon_F} \ln \frac{\epsilon_F}{\max [T, \omega_c (\omega_c \tau_{\text{tr}})^{1/2}]} \quad \text{overlapping LLs}$$

$$\frac{1}{\tau_{ee}} \sim \frac{\omega_c}{\Gamma} \frac{T^2}{\epsilon_F} \ln \frac{\epsilon_F}{\max [T, \Gamma (\omega_c \tau_{\text{tr}})^{1/2}]} \quad \text{separated LLs}$$

$$\implies \sigma_{\text{ph}} - \sigma_{\text{dc}} \propto T^{-2}$$

Two contributions to photoconductivity

- $\sigma_{\text{ph}}^{(1)}$: related to the change of the distribution function
 $\implies \propto \tau_{\text{in}}$, strongly T -dependent, independent of polarization \longrightarrow discussed above
- $\sigma_{\text{ph}}^{(2)}$: influence of microwave on impurity scattering,
 T -independent, polarization-dependent

Durst, Sachdev, Read, Girvin, PRL 2003
Vavilov, Aleiner, PRB 2004

$$\frac{\sigma_{\text{ph}}^{(1)}}{\sigma_{\text{ph}}^{(2)}} \sim \frac{\tau_{\text{in}}}{\tau_q} \gg 1 \quad \text{for relevant } T$$

Order-of-magnitude estimate of energy scales:

$$E_F \sim 100 \text{ K}$$

$$\tau_q^{-1} \sim 1 \text{ K}$$

$$T \sim 1 \text{ K}$$

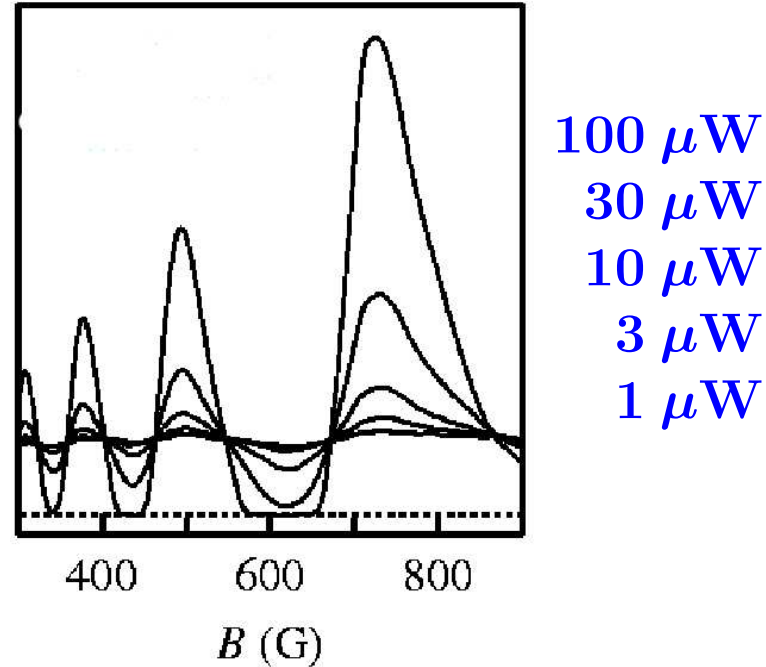
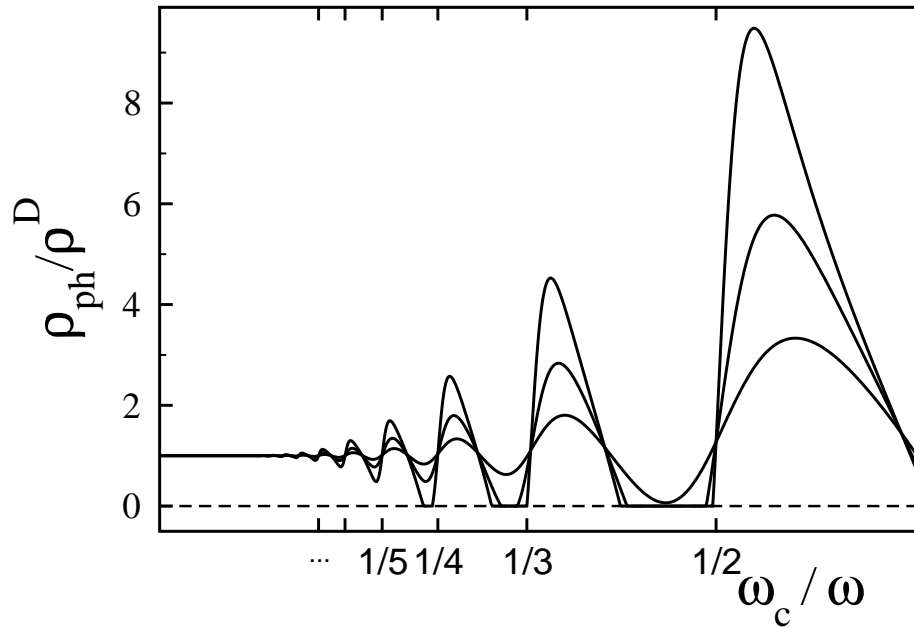
$$\omega \sim 1 \text{ K}$$

$$\tau_{\text{tr}}^{-1} \sim 10 \text{ mK}$$

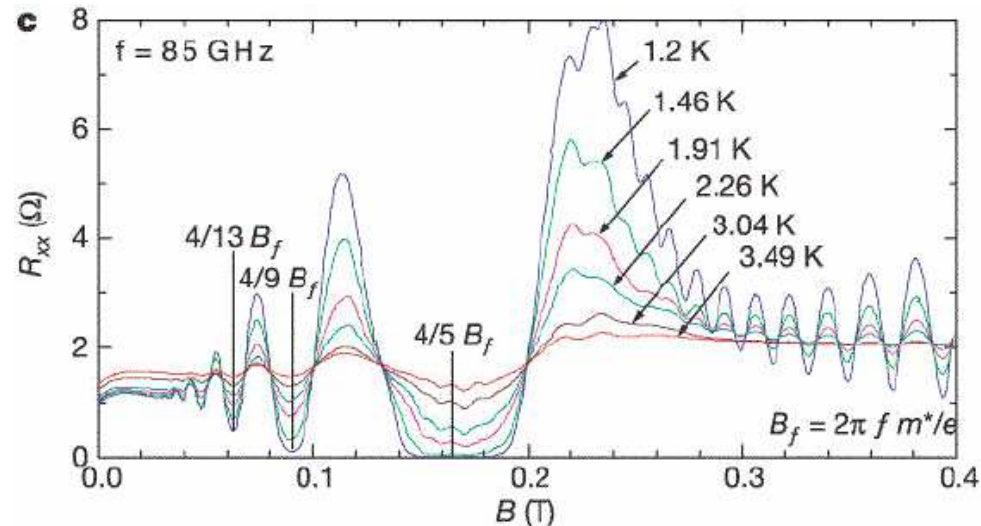
$$\tau_{\text{in}}^{-1} \sim \frac{T^2}{E_F} \sim 10 \text{ mK}$$

Theory vs experiment

$$\frac{\omega}{2\pi} \simeq 50 - 100 \text{ GHz}, \quad \tau_q \simeq 10 \text{ ps} \quad \longrightarrow \quad \frac{\omega\tau_q}{2\pi} \simeq 0.5 - 1 \quad (\text{overlapping LLs})$$



- Period, phase, shape – OK
- Independence of polarization – OK
- Temperature dependence at maximum $\propto \tau_{\text{in}} \propto T^{-2}$ – reasonably OK



Summary

- **Microwaves**
 - magnetooscillations in the 2DEG conductivity
 - negative linear-response conductivity
 - instability
 - domains
 - zero-resistance states
- **Parametrically largest contribution:**
Microwave-induced non-equilibrium distribution function.
- **Magnitude of the effect proportional to** $\tau_{\text{in}} \propto T^{-2}$
- **Future research (experimental and theoretical):**
 - detailed study of the domain physics
 - – effect of finite T on ZRS (experiment: activation?)
 - – noise in ZRS